







SN74LVC02A-Q1 SCES465E - JULY 2003 - REVISED MAY 2024

SN74LVC02A-Q1 Automotive Quadruple 2-Input Positive-NOR Gate

Technical

1 Features

- Qualified for automotive applications
- ESD protection exceeds 2000V per MIL-STD-883, Method 3015
- Inputs accept voltages to 5.5V

2 Description

The quadruple 2-input positive-NOR gate is designed for 2.7V to 3.6V V_{CC} operation.

The SN74LVC02A-Q1 performs the Boolean function $Y = \overline{A + B}$ or $Y = \overline{A} \cdot \overline{B}$ in positive logic.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V system environment.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾	BODY SIZE ⁽³⁾	
	BQA (WQFN, 14)	3mm × 2.5mm	3mm × 2.5mm	
SN74LVC02A-Q1	D (SOIC, 14)	8.65mm × 6mm	8.65mm × 3.9mm	
	PW (TSSOP, 14)	5mm × 6.4mm	5mm × 4.4mm	

For more information, see Section 10. (1)

(2) The package size (length × width) is a nominal value and includes pins, where applicable.

(3) The body size (length × width) is a nominal value and does not include pins.



Logic Diagram, Each Gate (Positive Logic)



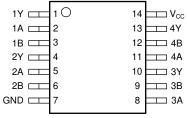
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3 Pin Configuration and Functions



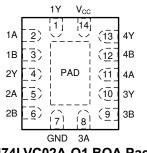
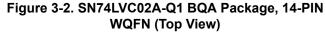


Figure 3-1. SN74LVC02A-Q1 D or PW Package, 14-Pin SOIC or TSSOP (Top View)



PIN			
NAME	SN74LVC02A -Q1	TYPE ⁽¹⁾	DESCRIPTION
	BQA, D, PW		
1Y	1	0	1Y Output
1A	2	I	1A Input
1B	3	Ι	1B Input
2Y	4	0	2Y Output
2A	5	Ι	2A Input
2B	6	Ι	2B Input
GND	7	_	Ground Pin
3A	8	I	3A Input
3B	9	Ι	3B Input
3Y	10	0	3Y Output
4A	11	Ι	4A Input
4B	12	Ι	4B Input
4Y	13	0	4Y Output
V _{CC}	14		Power Pin
NC	_	_	No Connection

(1) I = input, O = output



4 Specifications

4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V	
VI	Input voltage range ⁽¹⁾		-0.5	6.5	V	
Vo	Output voltage range ⁽¹⁾ ⁽²⁾		-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V ₁ < 0			-50	mA
I _{ОК}	Output clamp current	V _O < 0			-50	mA
lo	Continuous output current				±50	mA
	Continuous current through V _{CC} or GND				±100	mA
T _{stg}	Storage temperature range			-65	150	°C

(1) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(2) The value of V_{CC} is provided in the recommended operating conditions table.

4.2 ESD Ratings

			VALUE	UNIT
V (ESD)	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000	V

(1) AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

4.3 Recommended Operating Conditions

				MAX	UNIT
V	Supply voltage	Operating	2	3.6	V
V _{CC}	Supply Voltage	Data retention only	1.5		v
VIH	High-level input voltage	V _{CC} = 2.7V to 3.6V			V
VIL	Low-level input voltage	nput voltage V _{CC} = 2.7V to 3.6V		0.8	V
VI	V ₁ Input voltage		0	5.5	V
Vo	Output voltage			V _{CC}	V
	High-level output current	V _{CC} = 2.7V		-12	mA
юн	V _{CC} = 3V			-24	
		V _{CC} = 2.7V		12	mA
IOL	Low-level output current V _{CC} = 3V			24	IIIA
T _A Operating free-air temperature		-40	125	°C	

4.4 Thermal Information

THERMAL METRIC ⁽¹⁾					
		BQA (WQFN)	D (SOIC)	PW (TSSOP)	UNIT
		14 PINS	14 PINS	14 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	102.3	86	150.8	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC package thermal metrics* application report.



4.5 Electrical Characteristics

PARAMETER	TEST CONDITIONS	Vcc	MIN	TYP ⁽¹⁾ MAX	UNIT
V _{OH}	I _{OH} = -100μA	2.7V to 3.6V	$V_{CC} - 0.2$		
	L = 12mA	2.7V	2.2		V
	$I_{OH} = -12mA$	3V	2.4		v
	$I_{OH} = -24 \text{mA}$	3V	2.2		
	I _{OL} = 100μA	2.7V to 3.6V		0.2	
V _{OL}	I _{OL} = 12mA	2.7V		0.4	V
	I _{OL} = 24mA	3V		0.55	
I _I	V _I = 5.5V or GND	3.6V		±5	μA
I _{CC}	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	3.6V		10	μA
ΔI _{CC}	One input at V_{CC} – 0.6V, Other inputs at V_{CC} or GND	2.7V to 3.6V		500	μA
C _i	$V_{I} = V_{CC}$ or GND	3.3V		5	pF

over recommended operating free-air temperature range (unless otherwise noted)

(1) All typical values are at V_{CC} = 3.3V, T_A = 25°C.

4.6 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 2.7V	V _{CC} = 3.3V ±0.3V		UNIT
			MIN MAX	MIN	MAX	
t _{pd}	A or B	Y	6.5	1	5.5	ns

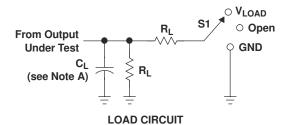
4.7 Operating Characteristics

T_A = 25°C

PARAMETER		TEST CONDITIONS	V _{CC} = 2.5V	V _{CC} = 3.3V	UNIT	
			ТҮР	TYP	UNIT	
	C _{pd} Power dissipation capacitance per gate	f = 10MHz	8.5	9.5	pF	

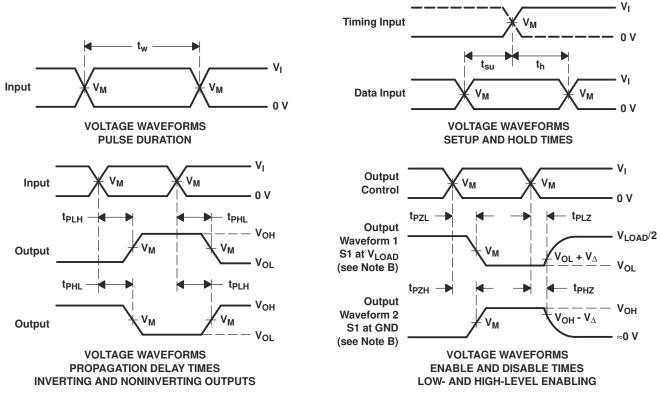


5 Parameter Measurement Information



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

	INPUTS		N	N.	•	_	
V _{CC}	VI	t _r /t _f	VM	V _{LOAD}	CL	RL	V_{Δ}
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3.3 V \pm 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V



- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
 Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 All input pulses are supplied by constrained by the following photoeteristical PDP < 10 MHz. 7 = 50.0
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω .
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 - H. All parameters and waveforms are not applicable to all devices.

Figure 5-1. Load Circuit and Voltage Waveforms



6 Detailed Description

6.1 Functional Block Diagram



Figure 6-1. Logic Diagram, Each Gate (Positive Logic)

6.2 Device Functional Modes

Function Table (Each Gate)								
INPUTS OUTPUT								
Α	В	Y						
Н	Х	L						
x	Н	L						
L	L	Н						



7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in given example layout image.

7.2 Layout

7.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC} , whichever makes more sense for the logic function or is more convenient.

7.2.2 Layout Example

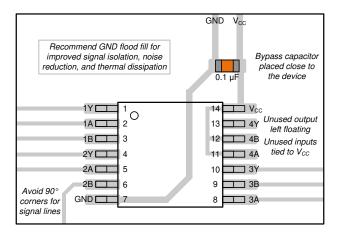


Figure 7-1. Example Layout for the SN74LVC02A-Q1

8 Device and Documentation Support

8.1 Documentation Support (Analog)

8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 9.1 Delated Links

PARTS PRODUCT FOLDER		SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY						
SN74LVC02A-Q1	Click here	Click here	Click here	Click here	Click here						

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

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8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision D (March 2024) to Revision E (May 2024)	Page
•	Updated RθJA values: PW = 113 to 150.8, all values in °C/W	4

С	hanges from Revision C (April 2008) to Revision D (March 2024)	Page
•	Added Package Information table, Pin Functions table, ESD Ratings table, Thermal Information table, D Functional Modes, Application and Implementation section, Device and Documentation Support section,	
•	Mechanical, Packaging, and Orderable Information section Added BQA package to Package Information table, Pin Configuration and Functions section, and Therm Information table	



10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•		Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material (6)	(3)		(4/5)	
SN74LVC02AQDRG4Q1	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC02AQ	Samples
SN74LVC02AQDRQ1	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC02AQ	Samples
SN74LVC02AQPWRG4Q1	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC02AQ	Samples
SN74LVC02AQPWRQ1	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC02AQ	Samples
SN74LVC02AWBQARQ1	ACTIVE	WQFN	BQA	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC02Q	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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OTHER QUALIFIED VERSIONS OF SN74LVC02A-Q1 :

- Catalog : SN74LVC02A
- Enhanced Product : SN74LVC02A-EP
- Military : SN54LVC02A

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications



Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC02AQPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC02AQPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC02AWBQARQ1	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1



www.ti.com

PACKAGE MATERIALS INFORMATION

9-Apr-2024



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC02AQPWRG4Q1	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LVC02AQPWRQ1	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LVC02AWBQARQ1	WQFN	BQA	14	3000	210.0	185.0	35.0

BQA 14

2.5 x 3, 0.5 mm pitch

GENERIC PACKAGE VIEW

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





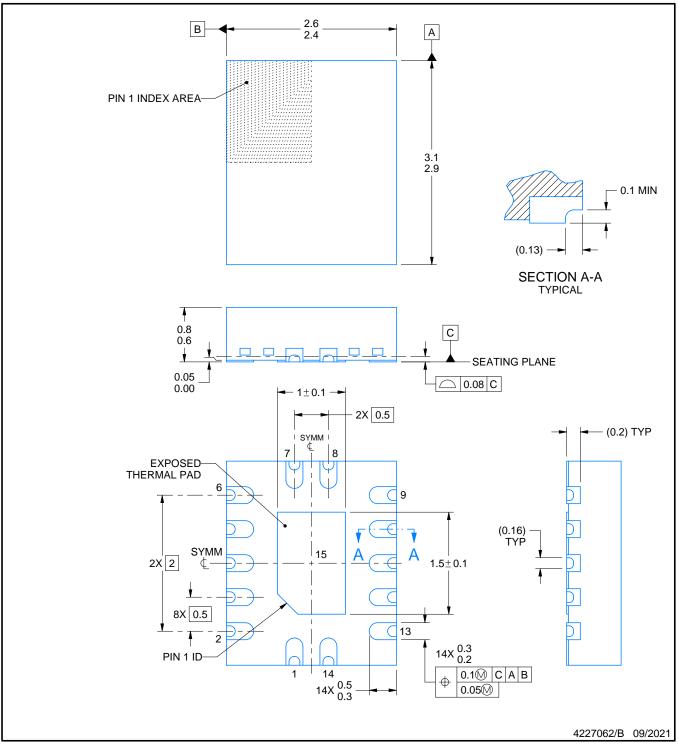
BQA0014B



PACKAGE OUTLINE

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

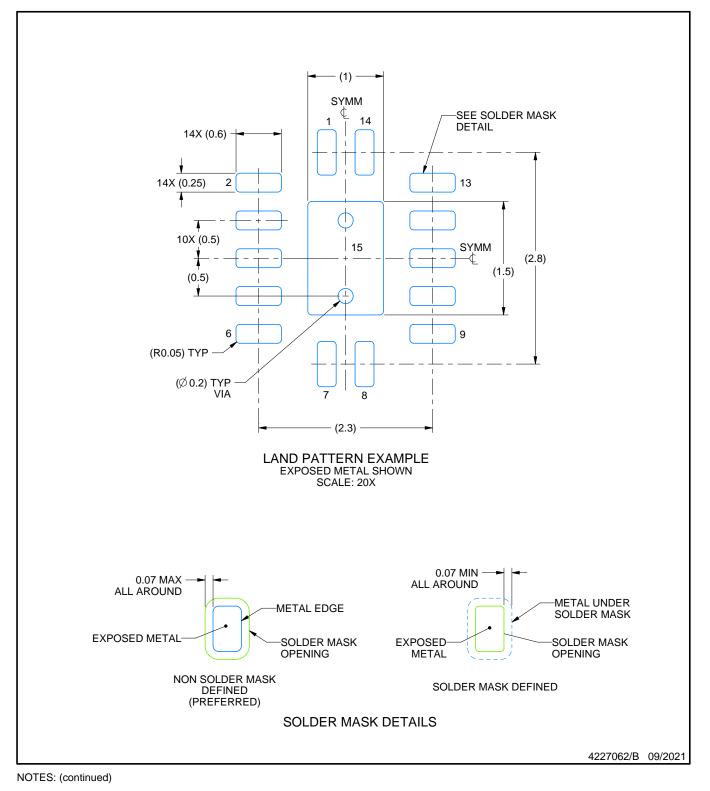


BQA0014B

EXAMPLE BOARD LAYOUT

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



 This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

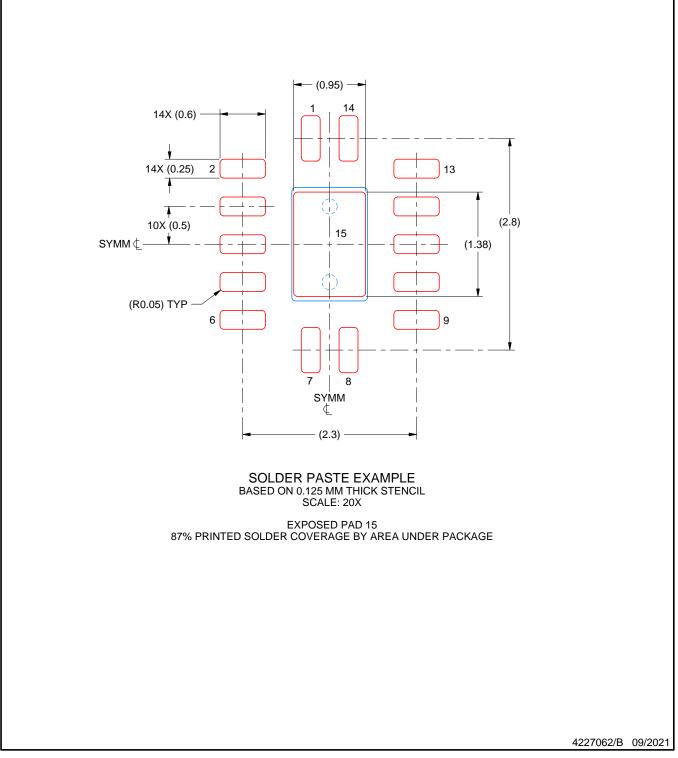


BQA0014B

EXAMPLE STENCIL DESIGN

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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